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SYNTHESIS AND CHARACTERIZATION OF AMPHOTERIC LIGANDS INCLUDING THE CRYSTAL AND MOLECULAR STRUCTURE OF [(Me₃SiCH₂)₂InPPh₂]₂ *

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Summary

The new amphoteric ligands $(Me_3SiCH_2)_2GaPPh_2$, $(Me_3SiCH_2)_2InPPh_2$, and $(Me_3CCH_2)_2InPPh_2$ have been prepared and characterized by elemental analyses, cryoscopic molecular weight measurements and ¹H NMR, ³¹P NMR and IR spectroscopic data. An X-ray structural study was carried out to define the nature of $[(Me_3SiCH_2)_2InPPh_2]_2$ in the solid state. The compounds were prepared either by a thermolysis reaction between the group 13 metal trialkyl and PPh₂H or by a metathetical reaction between the dialkylmetal halide and KPPh₂. Cryoscopic molecular weight measurements and ³¹P NMR spectroscopic data demonstrate that the new compounds exist as monomer-dimer equilibrium mixtures in benzene solution. The colorless crystal of $[(Me_3SiCH_2)_2InPPh_2]_2$ contains two discrete molecules of the dimer in each unit cell. The compound crystallizes in the triclinic space group $P\overline{1}$, with unit cell dimensions of a 10.323(4), b 11.113(5), c 21.509(8) Å, a 83.85(5), β 86.66(6), γ 83.27(5)° and ρ_{calcd} 1.29 g cm⁻³. Full matrix least-squares refinement led to a final R value of 0.035 for 3787 observed reflections. The molecule contains four-membered indium-phosphorus rings.

Introduction

Compounds of the general type $R_2MBR'_2$ in which M is a Lewis acid from group 13 and B is a group 15 Lewis base are of current interest. These compounds can remain as monomers with the potential for π -bonding [1], can associate to form dimers, trimers or higher oligomers [1] and/or can react as amphoteric ligands in

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transition metal organometallic chemistry [2]. In addition, some examples from this class of compounds have been used to make semiconductor materials by the MOCVD process [3].

A goal of our research is the elucidation of the effects of bulky ligands on the properties of main-group compounds. Since amphoteric molecules have two distinct parts, the acidic and the basic ends of the molecule, it is possible to introduce bulky substituents into one portion of the molecule and to investigate their effects on the chemistry of the amphoteric species. For example the presence of bulky substituents on the main-group metal might significantly alter its Lewis acidity but have minimal effects on the basicity of the group 15 atom. The compounds Me_2AlPPh_2 [4.6] and Et₂AlPPh₂ [5,6] exist as dimers in benzene solution and do not react with Cr(CO)₅NMe₁ [2]. The related molecule with bulky trimethylsilylmethyl substituents on aluminum exists as a monomer-dimer equilibrium mixture in benzene solution according to cryoscopic molecular weight measurements [6] and reacts readily with $Cr(CO)_{S}NMe_{1}$ to form $Cr(CO)_{S}[PPh_{2}Al(CH_{2}SiMe_{1})_{2} \cdot NMe_{1}]$ [2]. This reactivity pattern for this limited range of amphoteric organoaluminium-phosphorus ligands with Cr(CO), NMe₁ has been suggested to be related to the presence or absence of the monomeric ligand species [2]. In order to test this hypothesis further, the chemistry of related amphoteric molecules with other group 13 atoms should be investigated. The Lewis acidity of the amphoteric molecule should decrease in the order [1] Al > Ga > In, but the Lewis basicity of the PPh₂ portion of the molecule might not be expected to change significantly.

In this paper we report the synthesis and characterization of $(Me_3SiCH_2)_2GaP-Ph_2$, $(Me_3SiCH_2)_2InPPh_2$ and $(Me_3CCH_2)_2InPPh_2$. These compounds permit us to investigate the effects of the group 13 metal as well as to compare the effects of two closely related bulky substituents, trimethylsilylmethyl and neopentyl, on the properties of the amphoteric compounds. The compounds have been characterized by elemental analyses, cryoscopic molecular weight studies and IR, ¹H and ³¹P NMR spectroscopic data. The compound [$(Me_3SiCH_2)_2InPPh_2$]₂ has also been characterized by an X-ray structural study.

Experimental section

General data

All compounds described in this investigation were oxygen- and moisture-sensitive and were manipulated under purified argon or under vacuum. The solvents were purified by conventional means and were vacuum distilled prior to use. Analyses were performed by Schwarzkopf Microanalytical Laboratory, Woodside, NY. Infrared spectra of Nujol mulls between CsI plates were recorded by means of Perkin–Elmer Model 683 spectrometer. Absorption intensities are reported with abbreviations w (weak), m (medium), s (strong) and sh (shoulder). The ¹H NMR spectra were recorded at 90 and 270 MHz by using Varian Model EM-390 and JEOL Model FX 270 spectrometers, respectively. Chemical shifts are reported in δ units (ppm). ¹H NMR spectra are referenced to benzene at δ 7.13. The ³¹P{¹H} NMR spectra were recorded at 109.16 MHz by using a JEOL Model FX 270 spectrometer and are referenced to 85% H₃PO₄ at δ 0.00 ppm. The molecular weights were measured cryoscopically in benzene solution using an instrument similar to that described by Shriver [7]. Diphenylphosphine was purchased from Strem Chemicals, Inc. and was vacuum distilled prior to use. The reagents $Ga(CH_2SiMe_3)_3$ [8], $Ga(CH_2SiMe_3)_2Br$ [8], $In(CH_2SiMe_3)_3$ [9] and $KP(C_6H_5)_2$ [6] were prepared by literature procedures. The compounds $In(CH_2SiMe_3)_2Br$ and $In(CH_2SiMe_3)_2I$ were prepared by stoichiometric ligand redistribution reactions in benzene using the appropriate indium trihalide. $In(CH_2SiMe_3)_2Br$. m.p. 93.5–94.5°C. ¹H NMR (benzene) 0.36 s (2H, CH₂), 0.15 s (9H, Me). $In(CH_2SiMe_3)_2I$: m.p. 64–65.5°C. ¹H NMR (benzene) 0.64 s (2H, CH₂), 0.18 s (9H, Me).

Synthesis of $(Me_3SiCH_2)_2InPPh_2$

 $(Me_3SiCH_2)_2InPPh_2$ was synthesized by four methods. The preferred preparative route was the thermolysis of $In(CH_2SiMe_3)_3$ and PPh_2H in pentane. When this method was employed the indium phosphide precipitated from the reaction solution at 55°C as a colorless crystalline product which simplified purification of the product.

(a) From $In(CH_2SiMe_3)_3$ and PPh₂H in pentane. The reagents, 3.015 g (8.010 mmol) of In(CH₂SiMe₃)₃ and 1.492 g (8.013 mmol) of PPh₂H, were combined in a reaction tube equipped with a Teflon valve and stir bar using the dry box. The tube was evacuated and finally heated at 55°C for 3 d. Crystals of (Me₃SiCH₂)₂InPPh₂ formed during heating. The mixture was cooled to -78°C and the crystalline solid product isolated by filtration. Two washings with 10 ml of pentane at -20 °C provided colorless crystals of (Me₃SiCH₂)₂InPPh₂ (3.57 g, 7.53 mmol, 94.0% yield based on In(CH₂SiMe₃)₃). (Me₃SiCH₂)₂InPPh₂: m.p. 152°C (dec.). Anal. Found: C, 50.27; H, 6.67. calcd: C, 50.63; H, 6.80%. ¹H NMR (benzene, 0.42 m) δ 0.13 t (J 1.8 Hz, 2H, CH₂), 0.04s (9H, Me). ¹³C NMR (benzene) δ 2.98g (J 119 Hz, CH₂), -0.18 triplet of triplets (J_1 117, J_2 8 Hz, CH₂), (see Results and discussion.) ³¹P{¹H} NMR (benzene, 0.01m), (δ , (relative peak height), species: -29.1 s, (-), monomer; (benzene, 0.44 m) -29.15 s (12.23) monomer, -50.30 s, (1), dimer. IR (Nujol mull, cm⁻¹) 2320w, 1970vw, 1945vw, 1930vw, 1885vw,br, 1870vw, 1807vw, 1660w, 1642w, 1581m, 1480s, 1432s, 1353m, 1349m, 1322vw, 1300w, 1252m, 1240vs, 1180w, 1155w, 1092w, 1065w, 1024m, 967s, 960s, sh, 955s, 940s, 927m, 910w, 905vw,sh, 845vs, 837vs, 821vs, 740s,sh, 734vs, 712s, 689s, 681m,sh, 607vw, 570m, 552m, 500m, 489m, 471m, 440w, 345vw, 270w. Cryoscopic molecular weight, formula weight (Me₃SiCH₂),InPPh, 474.4 (calcd. molality, obs. molality, assoc.): 0.1267, 0.0801, 1.58; 0.0781, 0.0575, 1.36; 0.0565, 0.0436, 1.29; 0.1414, 0.0933, 1.52; 0.0873, 0.0630, 1.39; 0.0631, 0.0470, 1.34. Crystallographic quality crystals were obtained from a saturated pentane/benzene mixture (2/1) at 0 °C.

(b) From $In(CH_2SiMe_3)_3$ and PPh_2H in benzene. The compound $(Me_3SiCH_2)_2$ -InPPh₂ was prepared as described above except that the pentane was replaced by benzene. After the reaction mixture had been kept at 55°C for 7 d, the vessel was opened to the vacuum line and the SiMe₄ produced was collected by fractionation through two -78°C traps and isolation in a -196°C trap. The SiMe₄ (7.58 mmol, PVT measurements, 95% yield based on $In(CH_2SiMe_3)_3$) was identified by its ¹H NMR spectrum. The indium-phosphide was then washed out of the reaction tube with benzene and the benzene was finally removed by vacuum distillation. The remaining solid was recrystallized from 20 ml of pentane at -78°C to yield 3.534 g (7.449 mmol, 93.0% yield) of $(Me_3SiCH_2)_2InPPh_2$. The spectral properties of the indium-phosphide from this preparation were identical to the product obtained from reaction in pentane. (c) From KPPh₂ and $In(CH_2SiMe_3)_2Br$ in Et_2O . A solution of 0.823 g (2.23 mmol) of $In(CH_2SiMe_3)_2Br$ dissolved in 40 ml of Et_2O was combined with 0.500 g of KPPh₂ (2.23 mmol) with stirring over a 15 min period. Upon addition of the KPPh₂, a white precipitate formed immediately. The mixture was stirred for 24 h and then the ether was removed by vacuum distillation. The product mixture was extracted 5 times with 25 ml portions of pentane to separate the product from KBr. The indium phosphide was finally washed once with pentane at $-20^{\circ}C$. After the pentane was removed, 0.670 g (1.40 mmol), 62.7% yield based on $In(CH_2SiMe_3)_2Br)$ of $(Me_3SiCH_2)_2InPPh_2$ was isolated. Spectral properties of the indium phosphide obtained from this preparative route were identical to those obtained for the product from the thermolysis reaction in pentane. Similar results were obtained when $In(CH_2SiMe_3)_2I$ and KPPh₂ were used.

Synthesis of $(Me_3SiCH_2)_2GaPPh_2$

Potassium diphenylphosphide (0.465 g, 2.07 mmol) was slowly added during 10 min to a solution of 0.675 g (2.07 mmol) of $Ga(CH_2SiMe_3)_2Br$ at room temperature. A white precipitate formed upon the addition of KPPh₂. The mixture was then stirred for 10 h, then the Et₂O was removed by vacuum distillation and replaced by 40 ml of pentane. The gallium-phosphide was separated from KBr with 5 washings with 40 ml portions of pentane. Finally, after the pentane was removed 0.205 g (1.72 mmol, 83.1% yield based on KPPh₂) of KBr and 0.730 g (1.70 mmol, 82.1% based on KPPh₂) of (Me₃SiCH₂)₂GaPPh₂ had been separated. The gallium-phosphide was finally recrystallized from pentane at -78°C.

 $(Me_3SiCH_2)_2GaPPh_2$. Colorless, crystalline solid; m.p. 121–146 °C a glass forms that melts at 154–156 °C. Anal. Found: C, 55.64; H, 7.70. calcd: C, 55.94; H, 7.51%. Hydrolysis: 1.97 mol SiMe₄/mol (Me₃SiCH₂)₂GaPPh₂. IR (Nujol mull, cm⁻¹): 2420w, 1965vw, 1945vw, 1880vw, 1810vw, 1580m, 1575w,sh, 1350m, 1301m, 1251m,sh, 1240vs, 1170w, 1167w, 1154w, 1090w, 1065w, 1023m, 995s,sh, 985s, 963m, 947m, 912w, 848vs, 839s,sh, 820vs, 747s,sh, 737s,sh, 732vs, 718s, 690s, 680s,sh, 665m,sh, 613w, 583m, 558m, 524m, 500m, 476m, 458w, 440vw, 420vw, 390vw, 370vw, 320vw, 232vw. Cryoscopic molecular weight, formula weight (Me₃SiCH₂)₂GaPPh₂ 429.3 (calcd. molality, obs. molality, assoc.): 0.1545, 0.0808, 1.91; 0.0966, 0.0597, 1.61; 0.0702, 0.0456, 1.54. ¹H NMR (benzene, 0.54 m) δ 0.21 t (J 3.5 Hz, 2H, CH₂), 0.01 s (9H, Me). ³¹P{¹H} NMR δ , (relative peak height), species: (benzene, 0.1 m) -27.2 s (7.7), monomer; -40.4 s (1), dimer; (benzene, 0.01 m) -27.2 s (27.7), monomer; -40.25 s (1), dimer.

Reaction of $Ga(CH_2SiMe_3)_3$ and PPh_2H

The reagents, 1.063 g (3.208 mmol) of Ga(CH₂SiMe₃)₃ and 0.597 g (3.21 mmol) of PPh₂H, were combined in 8 ml benzene in a reaction tube equipped with a break-seal side arm. The tube was sealed, then placed in an oven and kept at 160–165 °C for 3 weeks. The break seal was then opened, and the volatile components were removed and fractionated through two -78 traps and -196 °C trap. The tetramethylisilane which formed during the reaction (1.77 mmol, PVT measurements, 55.1% based on PPh₂H) was collected in the -196 °C trap. Since the measurements of the evolved SiMe₄ indicated that the reaction was incomplete, the product was not isolated, but a ³¹P NMR spectrum of a benzene solution of the

resulting nonvolatile solid was recorded. ${}^{31}P{}^{1}H$ NMR benzene, δ , (relative peak height): -14.6 (1.0), -27.4 (1.8), -35.5 (3.1).

Reaction of $(Me_3SiCH_2)_2GaPPh_2$ and PPh_2H

The reagents, 0.100 g (0.233 mmol) of $(Me_3SiCH_2)_2GaPPh_2$ and 0.050 g (0.27 mmol) of PPh₂H were combined in an NMR tube using the dry box. Benzene was distilled into the tube which was then sealed under vacuum. ³¹P{¹H} NMR (benzene), δ , (relative peak height) -27.01, (1.0), -40.16, (2.1).

Reaction of $(Me_3SiCH_2)_2GaPPh_2$ with $Ga(CH_2SiMe_3)_3$

A mixture of $(Me_3SiCH_2)_2GaPPh_2$ (0.100 g, 0.233 mmol) and $Ga(CH_2SiMe_3)_3$ (0.105 g, 0.317 mmol) in 3 ml of benzene in a sealed NMR tube was observed by ³¹P NMR spectroscopy. ³¹P{¹H} NMR, (benzene), δ , (relative peak height) -14.1 (1), -26.7 (8).

Synthesis of (Me₃CCH₂)₂InPPh₂

The new compound (Me₃CCH₂)₂InPPh₂ was prepared from In(CH₂CMe₃)₃ (0.873 g, 2.66 mmol) and PPh₂H (0.495 g, 2.66 mmol) in benzene using the method previously described for $(Me_3SiCH_2)_2InPPh_2$. The mixture was kept at 60 °C for 3 d. The neopentane which formed during the reaction was separated from benzene by passage through two -78° C traps and was collected in a -196° C trap. Neopentane CMe₄ (2.57 mmol, PVT measurements, 96.6% yield based on In(CH₂CMe₃)₃) was isolated. The colorless solid remaining after the removal of the neopentane and benzene was washed once with 20 ml of pentane at -78 °C to leave $(Me_3CCH_2)_2InPPh_2$ (0.815 g, 1.84 mmol, 69.3% yield based on $In(CH_2CMe_3)_3$). (Me₃CCH₂)₂InPPh₂. m.p. 138–143°C a glass forms that decomposes at 143–150°C. Anal. Found: C, 59.74; H, 7.13. calcd.: C, 59.74; H, 7.29%. ¹H NMR (benzene, 0.40 m) 1.47 t (J 2.4 Hz, 1H, CH₂), 1.10 s (3.5H, CH₃), 1.03 s (1H, CH₃); (benzene, 0.20 m) 1.47 t (J 2.4 Hz, 1.2H, CH₂), 1.07 s (4.9H, CH₃), 1.03 s (1.0H, CH₃) (see Results and discussion) ${}^{31}P{}^{1}H{}$ NMR: (benzene, 0.28 m), δ , (relative peak height), species: -29.95 s (5.2) monomer, -49.40 (1.0) dimer; (benzene, 0.02 m) -29.95 s (5.4) monomer, -49.40 (1.0) dimer. IR (Nujol mull, cm⁻¹): 1960w, 1943w, 1875w, br, 1802w, 1740w, 1580m, 1567w, 1354s, 1297m, 1270w, br, 1230s, 1205w, sh, 1170w, 1160w,sh, 1150w, 1125vw, 1110w, 1096w, 1090w, 1061w, 1040vw, 1020w, 1009w, 998w, 965w, br, 907w, 890w, 840w, 765w, br, 736sh, 729vs, 717m, 687vs, 616s, 609m, 568m, 556m, sh, 540w, 497m, 468m, 445w, 430w, 375vw, 345w, 255w. IR (Kel-F mull): 3080w, 3060w, 2960vs, 2940s,sh, 2890m, 2870m, 2320w,br, 2200w, 1950vw, 1880vw,br, 1810w, 1785w, 1735w, 1585w, 1575w, 1478s,sh, 1470s, 1437s, 1440m,sh, 1385m, 1365s, 1360s. Cryoscopic molecular weight, formula weight (Me₃CCH₂)₂In-PPh₂ 442.25 (calcd. molality, obs. molality, assoc.): 0.175, 0.087, 2.01: 0.107, 0.057, 1.88; 0.077, 0.043, 1.80,

Crystallographic studies

A single crystal of $[(Me_3SiCH_2)_2InPPh_2]_2$ was sealed under N₂ in a thin-walled glass capillary. The crystal was mounted and data were collected on a Enraf-Nonius CAD-4 diffractometer by the $\omega/2\theta$ scan technique. The reflection data were corrected for Lorentz and polarization effects but not for absorption effects. A summary of the data collection parameters and final lattice parameters as de-

Compound	C., H., In, P. Si	
Mol. wt.	948.89	
Snace group	PĨ	
Cell constants		
	10 373(4)	
	11 112(5)	
	11.115(5)	
c (A)	21.509(8)	
α(°)	83.85(5)	
β(°)	86.66(6)	
γ (°)	83.27(5)	
Cell vol. (Å ³)	2433.72	
Molecules/unit cell (Z)	2	
ρ (calcd) (g cm ⁻³)	1.29	
μ (calcd) (cm ⁻¹)	11.23	
Radiation	Mo-K _a	
Max crystal dimens (mm)	0.40×0.30×0.25	
Scan width (°)	$0.8 \pm 0.2 \tan \theta$	
Std reflctns	600, 060, 0016	
Decay of stds	±2%	
Reflctns measd	4389	
$2(\theta)$ range	2–40 °	
Obsd refletns	3787	
No. of parameters varied	433	
GOF	1.09	
R	0.035	
<i>R</i> _w	0.042	

CRYSTAL DATA FOR $[Ph_2PInR_2]_2$ (R = CH₂SiMe₃)

termined from a least-squares refinement of $(\sin \theta/\lambda)^2$ values for 25 high angle reflections $(2\theta > 35^\circ)$ accurately centered on the diffractometer are given in Table 1.

Solution and refinement of the structure

The space group for the crystal, P1, was confirmed by the successful refinement. At first the centrosymmetric space group $P\overline{1}$ was selected to solve the structure but all attempts failed. The distribution of |E| values did not provide clear information whether or not the structure was centric. Then, the space group was changed to P1 and direct methods (MULTAN 80) [10] provided the four indium atoms. However, large correlations of related parameters appeared in the least-squares refinement. Therefore, the structure was transformed to the higher symmetry of $P\overline{1}$ by moving the origin of the unit cell. The coordinates of the other non-hydrogen atoms were obtained from the subsequent calculations of difference syntheses. Neutral atom scattering factors for C, In, P and Si were taken from Cromer and Waber [11]. The full-matrix least-squares refinement with isotropic temperature factors with the SHELX 76 [12] program system led to the reliability index of $R = \Sigma(|F_o| - |F_c|)/\Sigma|F_o| = 0.066$, then with anisotropic thermal parameters for all nonhydrogen atoms gave the final values of R = 0.035 and $R_w = {\Sigma w(|F_o| - |F_c|)/\Sigma w |F_o|^2}^{1/2} = 0.042$ based on 3787 observed reflections $(I > 2\sigma(I))$. The function minimized in the least-squares calculations was $\Sigma w |\Delta F|^2$ with unit

TABLE 1

weights. In the last cycle of refinement no parameters shifted by more than 0.005 of its estimated standard deviation. A final difference Fourier showed no feature greater than 0.34 $e/Å^3$. No effort to find hydrogen atoms was made. The final atom

Atom	x	у	Z
In(1)	0.92765(5)	0.37788(5)	0.56246(3)
In(2)	0.44974(5)	0.65226(5)	0.94433(3)
P(1)	0.9619(2)	0.6112(2)	0.5528(1)
P(2)	0.5481(2)	0.4254(2)	0.9344(1)
Si(1)	0.6168(2)	0.3707(2)	0.6323(1)
Si(2)	1.1016(2)	0.1209(2)	0.6351(1)
Si(3)	0.6225(3)	0.8333(2)	0.8335(1)
Si(4)	0.1388(3)	0.8056(3)	0.9380(1)
C(1)	0.7207(7)	0.3504(9)	0.5598(4)
C(2)	0.620(1)	0.223(1)	0.6826(5)
C	0.4438(9)	0.421(1)	0.6088(5)
C(4)	0.668(1)	0.491(1)	0.6794(5)
C(5)	1.0710(9)	0.2889(8)	0.6298(4)
C	1.279(1)	0.075(1)	0.6544(7)
$\vec{\alpha}$	1.000(1)	0.051(1)	0 7014(6)
C(8)	1.066(2)	0.056(1)	0.5617(6)
C(9)	1.0620(8)	0.6411(7)	0.6156(4)
C(10)	1.0236(9)	0.6077(9)	0.6150(4)
C(10)	1.0250())	0.632(1)	0.7759(5)
C(12)	1.100(1)	0.688(1)	0.7117(5)
C(12)	1.21-(1)	0.7187(9)	0.6500(5)
C(13)	1.2.32=(7)	0.6967(8)	0.6012(4)
C(15)	0.9127(9)	0.0907(8)	0.6012(4)
C(15)	0.0127(8)	0.7143(7)	0.5015(4)
C(10)	0.7073(8)	0.0901(9)	0.5257(4)
C(17)	0.389(1)	0.774(1)	0.5287(0)
C(10)	0.580(1)	0.806(1)	0.5682(7)
C(19)	0.084(1)	0.884(1)	0.6040(6)
C(20)	0.8010(9)	0.8078(8)	0.5999(5)
C(21)	0.5838(8)	0.7907(8)	0.9180(4)
C(22)	0.746(2)	0.717(1)	0.7987(6)
C(23)	0.698(1)	0.983(1)	0.8274(7)
C(24)	0.4/5(1)	0.857(2)	0.7861(7)
C(25)	0.2440(7)	0.6650(8)	0.9189(5)
C(26)	-0.028(1)	0.762(1)	0.9688(7)
C(27)	0.115(1)	0.912(1)	0.8648(6)
C(28)	0.209(1)	0.888(1)	0.9973(6)
C(29)	0.4466(8)	0.3507(8)	0.8865(4)
C(30)	0.4080(9)	0.408(1)	0.8294(5)
C(31)	0.329(1)	0.348(1)	0.7932(5)
C(32)	0.291(1)	0.236(1)	0.8162(7)
C(33)	0.329(1)	0.182(1)	0.8736(8)
C(34)	0.408(1)	0.238(1)	0.9100(5)
C(35)	0.7113(8)	0.4078(8)	0.8966(5)
C(36)	0.742(1)	0.327(1)	0.8510(5)
C(37)	0.871(2)	0.315(2)	0.8243(8)
C(38)	0.962(2)	0.382(2)	0.846(1)
C(39)	0.934(1)	0.461(1)	0.8910(9)
C(40)	0.8029(9)	0.4761(9)	0.9189(6)

FINAL FRACTIONAL COORDINATES FOR [(Me₃SiCH₂)₂InPPh₂]₂

TABLE 2

coordinates are given in Table 2. Tables of thermal parameters and lists of observed and calculated structure factors are available from the authors.

Results and discussion

A series of new amphoteric molecules, $(Me_3SiCH_2)_2InPPh_2$, $(Me_3CCH_2)_2In-PPh_2$ and $(Me_3SiCH_2)_2GaPPh_2$ have been prepared and characterized. The characterization data include elemental analyses, cryoscopic molecular weight measurements as well as IR, ¹H and ³¹P NMR spectroscopic data. A variety of data for benzene solutions of the new compounds suggest that they exist as equilibrium mixture of monomers and dimers. In contrast, the X-ray structural study reveals the presence of the dimer, $[(Me_3SiCH_2)_2InPPh_2]_2$, in the solid state.

The organometallic phosphides were prepared by two methods: (i) the thermolysis of a mixture of MR_3 and PPh_2H (eq. 1) and (ii) the metathetical reaction between R_2MBr and $KPPh_2$ (eq. 2). However, the preferred method for the preparation of the indium phosphides was the thermolysis, but the metathetical reaction was more useful for preparing (Me_3SiCH_2)_2GaPPh_2. The extent of the

$$MR_{3} + PPh_{2}H \xrightarrow{C_{5}H_{12}}{\text{or }C_{6}H_{6}} R_{2}MPPh_{2} + RH$$
(1)

$$MR_{2}Br + KPPh_{2} \xrightarrow{Et_{2}O} R_{2}MPPh_{2} + KBr_{(s)}$$
(2)

thermolysis reaction was determined by the isolation of pure RH (SiMe₄, R = CH₂SiMe₃ and CMe₄, R = CH₂CMe₃). For the reactions of organoindium compounds the yields of RH were typically > 95%. However, when Ga(CH₂SiMe₃)₃ was used, SiMe₄ was produced in < 60% yield, even after heating at 160–165 °C for 3 weeks. In the case of metathetical reactions, KBr was usually isolated in > 80% yields. When a given compound was prepared by both methods, identical chemical and spectroscopic properties were observed for the products. However, it is noteworthy the melting points of these amphoteric metal-phosphides are not useful for estimating the purity of a sample; the organoindium compounds decompose before melting and the gallium-phosphide undergoes a transition to a glass before melting. The presence of the glass makes the observation of the melting point difficult and possibly unreliable. Similar phase changes have been observed for (Me₃SiCH₂)₂Al-PPh₂ [6] as well as for other examples of this class of compound [4,13,14]. These glass transitions have been suggested to be due to changes in the degree of association [13,14].

The thermolysis of Ga(CH₂SiMe₃)₃ and PPh₂H produced SiMe₄ in < 60% yield. Even prolonged heating of a reaction mixture at 160–165 °C did not drive the reaction to completion. Other attempts to complete the elimination by raising the temperature above 165 °C led to the decomposition of the gallium-phosphide product. The cause of the incomplete elimination of SiMe₄ from Ga(CH₂SiMe₃)₃ and PPh₂H was investigated by using ³¹P NMR spectroscopy. The data suggest that the formation of an adduct between (Me₃SiCH₂)₂GaPPh₂ and Ga(CH₂SiMe₃)₃ reduces the concentration of free Ga(CH₂SiMe₃)₃ available for an elimination reaction with PPh₂H, thereby slowing the rate of the elimination. (These results are discussed fully later in the discussion.) As the amount of (Me₃SiCH₂)₂GaPPh₂ increases, the concentration of the adduct increases, and the rate of reaction



Fig. 1. Labeling of atoms in $[(Me_3SiCH_2)_2InPPh_2]_2$ (Molecule A) ORTEP-II diagram showing 30% probability contours of the thermal vibration ellipsoids of non-hydrogen atoms.

decreases further. The formation of an adduct between an organometallic phosphide and a group 13 alkyl has also been invoked to explain kinetic data and the long times required for complete conversion of $AlMe_2H-P(Me)(Ph)H$ mixture into H_2 and $Me_2AlP(Me)(Ph)$ [15].

The crystal of [(Me₃SiCH₂)₂InPPh₂]₂ consists of discrete isolated molecules. There are two molecules in the unit cell, and each lies on a crystallographic center of inversion. Molecule A with the atom numbering scheme is shown in Fig. 1; the structure of molecule B is very similar to that of molecule A. However, the dimensions of the four-membered indium-phosphorus rings of the two kinds of molecules are slightly different. In molecule A the non-bonding distance of $In \cdots In'$ and $P \cdots P'$, within the rings are 3.9670(7) and 3.524(3) Å, whereas in molecule B are 3.9992(7) and 3.464(3) Å, respectively. Bond distances and angles are listed in Table 3. From this comparison, slight differences are apparent: the angles P-In-P' 83.23(7) and In-P-In' 96.77(7)° in molecule A while 81.80(7) and 98.20(8)°. respectively, are found in molecule B. The In-P distance vary from 2.632(2) to 2.664(2) Å and all these values are shorter than the mean value of 2.712 Å for bis(triphenylphosphine)-trichloroindium(III) [16]. The In-C bond lengths vary from 2.196(8) to 2.209(8) Å, (average 2.202(8) Å). These are close to those found for other organoindium compounds, such as InMe₃ (2.12, 2.06, 2.15 Å) [17], Et₂InOOCMe₃ (2.22, 2.29 Å) [18], Me₂InOOCMe₃ (2.11, 2.08 Å) [19], (Me₂InNMe₂)₂ (2.168, 2.170 Å) [20] and [Me₂InN(Me)(Ph)]₂ (2.149, 2.156 Å) [21]. The C-In-C angles are wide,

TABLE 3

BOND LENGTHS (Å) AND BOND ANGLES (°) FOR [(Me₃SiCH₂]₂InPPh₂]₂ IN TWO INDEPENDENT MOLECULES

	Molecule A	Molecule B	
In-P	2.643(2)	2.632(2)	
In-P'	2.664(2)	2.659(2)	
ln-C(1)	2.198(7)	2.196(8)	
In-C(5)	2.206(8)	2.209(8)	
P-C(9)	1.829(8)	1.832(9)	
P-C(15)	1.821(8)	1.826(8)	
Si(1) - C(1)	1.860(8)	1.861(9)	
Si(1)-C(2)	1.86(1)	1.89(1)	
Si(1) - C(3)	1.89(1)	1.91(1)	
Si(1) - C(4)	1.90(1)	1.86(1)	
Si(2)-C(5)	1.848(9)	1.864(9)	
Si(2)-C(6)	1.90(1)	1.91(1)	
Si(2) - C(7)	1.87(1)	1.88(1)	
Si(2) - C(8)	1.87(1)	1.87(1)	
C(9) - C(10)	1.38(1)	1.38(1)	
C(9) = C(14)	1.40(1)	1 39(1)	
C(10) - C(11)	1.42(1)	1.43(1)	
C(11) - C(12)	1.40(1)	1 37(2)	
C(12) - C(13)	1.36(1)	1 38(2)	
C(13) - C(14)	1.42(1)	1 40(2)	
C(15) = C(16)	141(1)	1 40(1)	
C(15) = C(20)	1 39(1)	1.40(1)	
C(16) - C(17)	1.35(1)	1.47(1)	
C(17) = C(18)	141(2)	1.42(2)	
C(18) - C(19)	1.40(2)	1 37(2)	
C(19)-C(20)	1.39(1)	1.45(2)	
P-In-P'	83.23(7)	81.80(7)	
P-In-C(1)	112.1(3)	115.7(2)	
P'-In-C(1)	110.1(2)	112.3(2)	
P-In-C(5)	104.9(2)	106.1(2)	
P'-In-C(5)	109.6(2)	106.0(2)	
C(1) - In - C(5)	127.8(3)	125.9(3)	
In-P-In'	96.77(7)	98.20(8)	
In-P-C(9)	110.0(3)	110.8(3)	
In'-P-C(9)	116.9(3)	116.6(3)	
In-P-C(15)	114.8(3)	114.8(3)	
In'-P-C(15)	114.4(3)	111.8(3)	
C(9)-P-C(15)	104.3(4)	105.0(4)	
C(1)-Si(1)-C(2)	109.8(5)	112.1(5)	
C(1)-Si(1)-C(3)	108.0(4)	107.1(5)	
C(2)-Si(1)-C(3)	109.0(5)	107.8(7)	
C(1)-Si(1)-C(4)	113.2(4)	112.6(5)	
C(2)-Si(1)-C(4)	109.1(6)	108.7(8)	
C(3)-Si(1)-C(4)	107.6(6)	108.3(8)	
C(5) - Si(2) - C(6)	108.2(5)	108.7(5)	
C(5)-Si(2)-C(7)	110.5(5)	109.4(5)	
C(6)-Si(2)-C(7)	106.4(6)	107.8(6)	
C(5)-Si(2)-C(8)	113.4(5)	113.3(4)	
C(6)-Si(2)-C(8)	109.9(7)	109.2(7)	
C(7)-Si(2)-C(8)	108.2(6)	108.3(6)	
In-C(1)-Si(1)	117.3(4)	118.9(4)	

TABLE 3 (continued)

	Molecule A	Molecule B	
$\overline{\text{In-C(5)-Si(2)}}$	117.0(4)	115.8(4)	
P-C(9)-C(10)	119.1(6)	119.5(7)	
P-C(9)-C(14)	120.0(6)	118.5(8)	
C(10)-C(9)-C(14)	120.9(8)	122.0(9)	
C(9)-C(10)-C(11)	119.4(9)	118(1)	
C(10)-C(11)-C(12)	120(1)	120(1)	
C(11)-C(12)-C(13)	120.0(9)	121(1)	
C(12)-C(13)-C(14)	120.9(9)	121(1)	
C(9)-C(14)-C(13)	118.9(9)	118(1)	
P-C(15)-C(16)	116.7(6)	120.9(8)	
P-C(15)-C(20)	122.8(7)	115.4(8)	
C(16)-C(15)-C(20)	120.5(8)	123.6(9)	
C(15)-C(16)-C(17)	120.0(9)	119(1)	
C(16)-C(17)-C(18)	118(1)	118(2)	
C(17)-C(18)-C(19)	121(1)	124(2)	
C(18)-C(19)-C(20)	120(1)	119(2)	
C(15)-C(20)-C(19)	120(1)	117(1)	

at 127.8(3) and 125.9(3)°, because of steric hindrance between the bulky CH_2SiMe_3 groups. Figure 2 shows the packing of molecules in the unit cell. No short contacts are noted.

The apparent degree of association of each compound R_2MPPh_2 (M = Ga, $R = CH_2SiMe_3$; M = In, $R = CH_2SiMe_3$, CH_2CMe_3) in benzene solution was studied by means of cryoscopic molecular weight measurements. These studies indicate that monomer-dimer equilibria occur in benzene solution. The average degree of association of the trimethylsilylmethyl derivatives at a given concentration decreases in the order Al [5] > Ga > In. This order follows the order expected on the basis of Lewis acidity. It is also of interest that the neopentylindium derivative is more associated than the corresponding trimethylsilylmethyl derivative. The observations of the higher degree of association of the neopentyl compounds compared with that of the CH₂SiMe₃ derivatives might suggest that the electronic effects of the neopentyl group enhance the Lewis acidity of the group 13 atom. Alternatively, the neopentyl group would have to be sterically less demanding than the trimethylsilylmethyl group, which is inconsistent with the general literature. Calculations using group electronegativities [22] indicate that a higher positive charge is located on the metallic center of the neopentyl-indium phosphide than on the indium of the trimethylsilylmethyl derivative. Consequently, the neopentyl derivatives are expected to have a greater Lewis acidity than their trimethylsilylmethyl analogs.

The relative heights of the peaks in ³¹P NMR spectra of the organometallic phosphides R_2MPPh_2 (M = Ga, R = CH₂SiMe₃; M = In, R = CH₂SiMe₃, CH₂CMe₃) are concentration dependent over the concentration range from 0.01 to 0.50 *m* and are consistent with the occurrence of monomer-dimer equilibria. A typical spectrum consists of two resonances: one at approximately -30 ppm, and the second between -40 and -50 ppm. The relative peak heights of the upfield resonance to the downfield resonance increased as the concentration of the organometallic phosphide increased, but the chemical shifts did not change. These

observations suggest that the upfield signal is due to the phoshorus atoms of the dimeric species and the downfield signal to the monomeric species. In the case of $(Me_3SiCH_2)_2InPPh_2$, only the monomeric species was observed at low concentrations, whereas resonances for both the monomeric and dimeric species were observed at all concentrations studied for $(Me_3SiCH_2)_2GaPPh_2$ and $(Me_3CCH_2)_2In-PPh_2$. These observations are consistent with group electronegativity calculations [22] of partial charges on gallium and indium. The indium atom in $(Me_3SiCH_2)_2In-PPh_2$ has the lowest calculated partial positive charge and the lowest degree of association.

The presence of an adduct of the gallium-phosphide with $Ga(CH_2SiMe_3)_3$, $(Me_3SiCH_2)_2GaPPh_2 \cdot Ga(CH_2SiMe_3)_3$, among the thermolysis products from $Ga(CH_2SiMe_3)_3$ and PPh₂H was suggested by comparing the ³¹P{¹H} NMR spectrum of the thermolysis mixture with that for pure (Me₃SiCH₂)₂GaPPh₂ and for mixtures of pure (Me₃SiCH₂)₂GaPPh₂ with added Ga(CH₂SiMe₃)₃ or with added PPh₂H. The ³¹P NMR spectrum of the product mixture after thermolysis (no purification) exhibited resonances at -14.6, -27.4 and -35.5 ppm, which are assigned to $(Me_3SiCH_2)_2GaPPh_2 \cdot Ga(CH_2SiMe_3)_3$, monomeric $(Me_3SiCH_2)_2$ -GaPPh₂ and an unknown species, respectively. The line at -14.6 ppm which is attributed to $(Me_3SiCH_2)_2GaPPh_2 \cdot Ga(CH_2SiMe_3)_3$ has a very similar shift to that of the line at -14.6 ppm in the spectrum of a mixture (Me₃SiCH₂)₂GaPPh₂ and $Ga(CH_2SiMe_3)_3$. The resonance for the phosphorus atom in this adduct would be expected to be downfield of the resonance for monomeric (Me₃SiCH₂)₂GaPPh₂ (-27.2 ppm) because the phosporus is bonded to an electron-withdrawing Lewis acid, Ga(CH₂SiMe₁)₁. The chemical shift of the resonance at -27.4 ppm is very similar to that observed for monomeric (Me₃SiCH₂)₂GaPPh₂ (-27.2 ppm). The line at -35.5 remains unassigned; it cannot be related to PPh₂H · (Me₃SiCH₂)₂-



Fig. 2. Stereoscopic view of the unit cell of [(Me₃SiCH₂)₂InPPh₂]₂.

GaPPh₂ because the ³¹P NMR spectrum of a mixture of $(Me_3SiCH_2)_2GaPPh_2$ and PPh₂H has only lines at -27.0 and -40.2 ppm, which are due to the reactants.

The ¹H NMR spectra of R_2MPPh_2 (M = In, CH₂SiMe₃, CH₂CMe₃; Ga, CH₂SiMe₃) consists of an apparent triplet downfield from a strong singlet (s). In the case of (Me₃CCH₂)₂InPPh₂, two closely spaced singlets were well resolved but an expanded scale spectrum was required to observe two closely spaced singlets for (Me₃SiCH₂)₂MPPh₂ (M = Ga, In). The new line was of significantly lower intensity than the initial singlet. On the basis of the relative intensities the apparent triplet has been assigned to the methylene protons whereas the singlets are due to methyl protons. However, it is not possible to assign lines to the monomer or the dimer or to relate the multiplicity of lines to restricted rotation or to proton-phosphorus coupling. The concentration dependence of the spectra over the range from about 0.1 to 0.5 *m* was investigated but no definitive changes in the spectra were noticed. Similarly, no significant changes were observed over the temperature range from -45 to +55°C. Even use of 270 MHz spectra failed to provide more definitive data. Consequently, no attempt will be made to interpret the currently available data further.

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